



## SS12 THRU SS100

1.0 AMP. SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS



### FEATURES

- \* For surface mounted application
- \* Metal to silicon rectifier, majority carrier conduction
- \* Low forward voltage drop
- \* Easy pick and place
- \* High surge current capability
- \* Plastic material used carries Underwriters Laboratory classification 94V-O
- \* Epitaxial construction
- \* Extremely Low Thermal Resistance

### MECHANICAL DATA

- \* CASE: Molded plastic
- \* Terminals: Solder plated
- \* Polarity: Indicated by cathode band
- \* Packaging: 12mm tape per EIA STD RS-481
- \* Weight: 0.091 grams (SMA/DO-214AC\*)  
0.064 grams (SMA/DO-214AC)

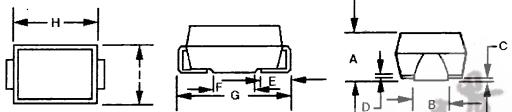
### VOLTAGE RANGE

20 to 100 Volts

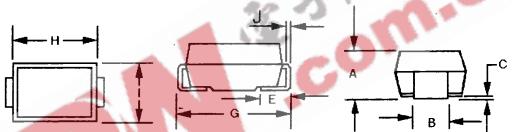
### CURRENT

1.0 Ampere

### SMA/DO-214AC\*



### SMA/DO-214AC



### DIMENSIONS

SMA/DO-214AC*		SMA/DO-214AC	
inches	mm	inches	mm
A .078 to .090(L)	1.98 to 2.29(L)	.078 to .090	1.98 to 2.29
A .110 to .117(H)	2.80 to 2.98(H)		
B .067 to .088	1.7 to 2.24	.052 to .058	1.32 to 1.47
C .006MAX	.02MAX	.008MAX	.02MAX
D .02MAX	.51MAX		
E .030 to .060	.76 to 1.52	.030 to .050	.76 to 1.27
F .067 to .094	1.65 to 2.39		
G .204 to .220	5.21 to 5.59	.194 to .208	4.93 to 5.28
H .160 to .179	4.06 to 4.55	.157 to .177	3.99 to 4.50
I .101 to .112	2.56 to 2.85	.100 to .110	2.54 to 2.79
J		.006 to .012	.152 to .305

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

TYPE NUMBER	SYMBOLS	SS12	SS13	SS14	SS15	SS16	SS18	SS100	UNITS
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	80	100	V
Maximum RMS Voltage	$V_{RMS}$	14	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	$V_{DC}$	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current $T_L = 90^\circ\text{C}$ (NOTE 2)	$I_{F(AV)}$				1.0				A
Peak Forward Surge Current, 8.3ms half sine	$I_{FSM}$				30				A
Maximum Instantaneous Forward Voltage @ 1.0A (NOTE 1)	$V_F$		0.55		0.70		0.85		V
Maximum D.C Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated D.C. Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_R$			0.5	20				mA
Typical Thermal Resistance (NOTE 2)	$R_{\theta JL}$			35					°C/W
Typical Junction Capacitance (NOTE 3)	$C_J$			130					pF
Operating and Storage Temperature Range	$T_J / T_{STG}$			-65 to +125	/ -65 to +150				°C

NOTE 1. Pulse test width 300  $\mu\text{sec}$ , Duty cycle 2%

2. P.C. B mounted with  $0.2 \times 0.2''(5 \times 5\text{mm})$  copper pad areas

3. Measured at 1MHz and applied  $V_R = 4.0\text{V D.C.}$

### RATINGS AND CHARACTERISTIC CURVES (SS12 THRU SS100)

Figure 1 – TYPICAL FORWARD CHARACTERISTICS

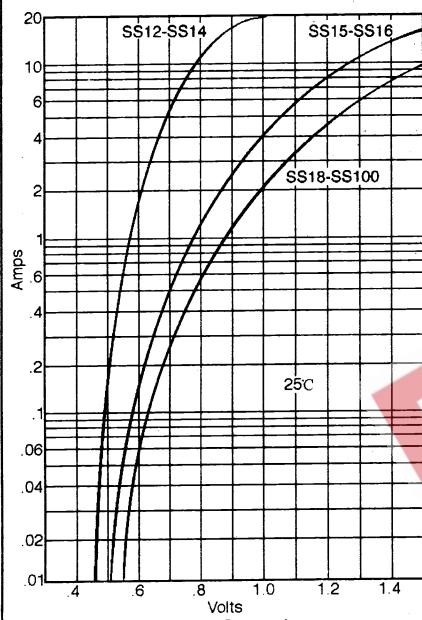


Figure 2 – TYPICAL JUNCTION CAPACITANCE

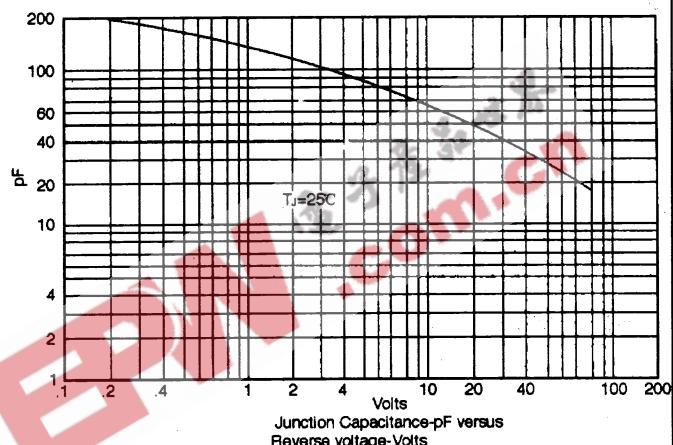


Figure 4 – MAXIMUM NON – REPETITIVE SURGE CURRENT

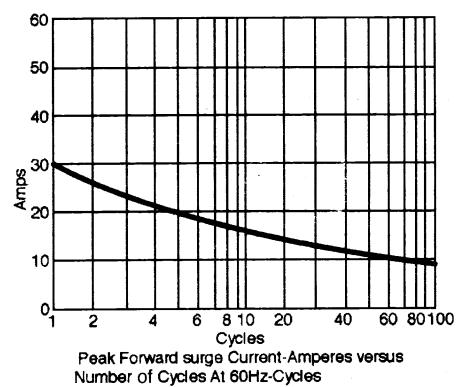
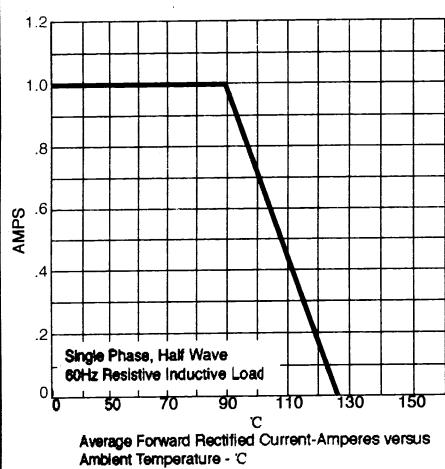


Figure 3 – FORWARD CURRENT DERATING CURVE



### SUGGESTED SOLDER PAD LAYOUT

